



DVRN6056

VOLTAGE REFERENCE ARRAY

Features

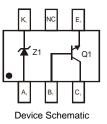
- Epitaxial Planar Die Construction
- Ideally Suited for Automated Assembly Processes
- Lead Free/RoHS Compliant Version (Notes 2 & 3)
- "Green" Device (Note 3)

Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding Compound (Note 3) UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Matte Tin Finish annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)



Top View



Maximum Ratings, NPN Transistor Element (Q1) @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current - Continuous (Note 1) I _C	600	mA

Maximum Ratings, Zener Element (Z1) @T_A = 25°C unless otherwise specified

C	haracteristic	Symbol	Value	Unit
Forward Voltage	@ I _F = 10mA	V _F	0.9	V

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 1)	PD	300	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{\theta JA}$	417	°C/W
Operating and Storage Temperature Range		TJ, T _{STG}	-55 to +150	°C

Notes: 1. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf. 2. No purposefully added lead.

3. Product manufactured with date code WN (Week 45, 2009) and newer are built with Green Molding Compound and Lead-free plating. Product

manufactured prior to date code WO are built with Tin-Lead plating, Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.



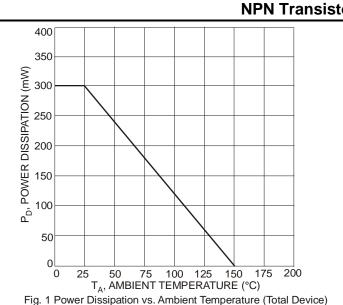
Electrical Characteristics, NPN Transistor Element (Q1) @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)			1	•	•
Collector-Base Breakdown Voltage	V _{(BR)CBO}	60		V	$I_{C} = 100 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	40		V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0	_	V	$I_{E} = 100 \mu A, I_{C} = 0$
Collector Cutoff Current	ICEX	_	100	nA	$V_{CE} = 35V, V_{EB(OFF)} = 0.4V$
Base Cutoff Current	I _{BL}		100	nA	$V_{CE} = 35V, V_{EB(OFF)} = 0.4V$
ON CHARACTERISTICS (Note 4)					· · · · · ·
		20			$I_{C} = 100 \mu A, V_{CE} = 1.0 V$
		40			$I_{C} = 1.0 \text{mA}, V_{CE} = 1.0 \text{V}$
DC Current Gain	h _{FE}	80			$I_{C} = 10 \text{mA}, V_{CE} = 1.0 \text{V}$
		100	300		$I_{C} = 150 \text{mA}, V_{CE} = 1.0 \text{V}$
		40	—		$I_{C} = 500 \text{mA}, V_{CE} = 2.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.40	V	I _C = 150mA, I _B = 15mA
	VCE(SAT)		0.75		$I_{\rm C} = 500$ mA, $I_{\rm B} = 50$ mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	0.75	0.95	V	I _C = 150mA, I _B = 15mA
	VBE(SAT)	_	1.2	v	$I_{\rm C} = 500$ mA, $I_{\rm B} = 50$ mA
SMALL SIGNAL CHARACTERISTICS			i	i	i
Output Capacitance	C _{cb}		6.5	pF	$V_{CB} = 5.0V, f = 1.0MHz, I_E = 0$
Input Capacitance	Ceb		30	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$
Input Impedance	h _{ie}	1.0	15	kΩ	
Voltage Feedback Ratio	h _{re}	0.1	8.0	x 10 ⁻⁴	V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz
Small Signal Current Gain	h _{fe}	40	500	_	$V_{CE} = 10V, I_{C} = 1.011A, I = 1.0KHZ$
Output Admittance	h _{oe}	1.0	30	μS	
Current Gain-Bandwidth Product	f⊤	250	_	MHz	V _{CE} = 10V, I _C = 20mA, f = 100MHz
SWITCHING CHARACTERISTICS					
Delay Time	t _d	_	15	ns	$V_{CC} = 30V, I_C = 150mA,$
Rise Time	tr		20	ns	$V_{BE(off)} = 2.0V, I_{B1} = 15mA$
Storage Time	ts	_	225	ns	$V_{CC} = 30V, I_{C} = 150mA,$
Fall Time	t _f		30	ns	$I_{B1} = I_{B2} = 15 \text{mA}$

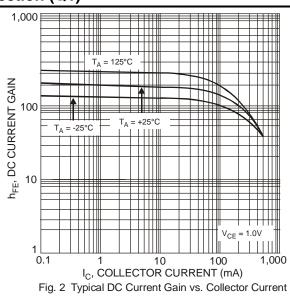
Electrical Characteristics, Zener Element (Z1) @TA = 25°C unless otherwise specified

Zener Voltage Range (Note 4)			Maxir	num Zener Impedance	Maximum Reverse Leakage Current (Note 4)		
	Vz @ Izt Izt			Z _{ZT} @ I _{ZT}	Z _{ZK} @ I _{ZK} = 0.5mA	I _R	@ V _R
Nom (V)	Min (V)	Max (V)	mA	Ω		μA	V
5.6	5.49	5.73	5	60	200	1.0	2.5

Notes: 4. Short duration pulse test used to minimize self-heating effect.

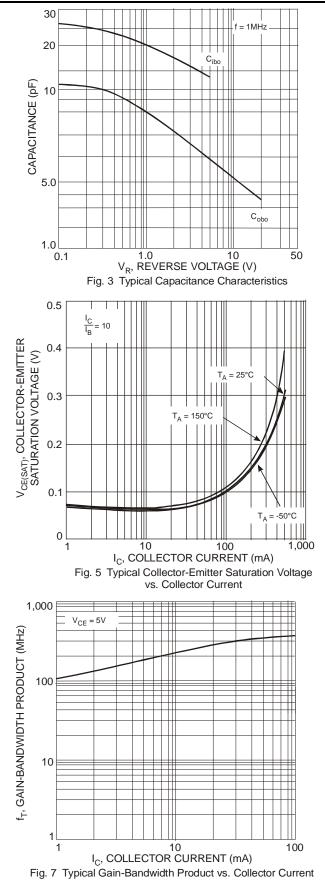


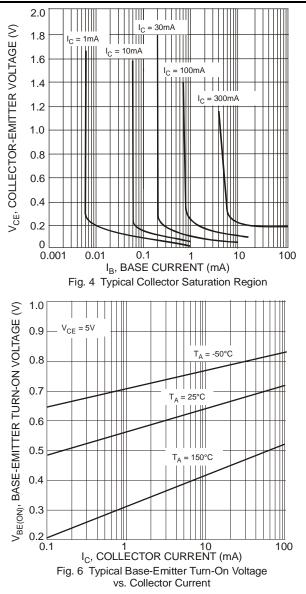
NPN Transistor Section (Q1)





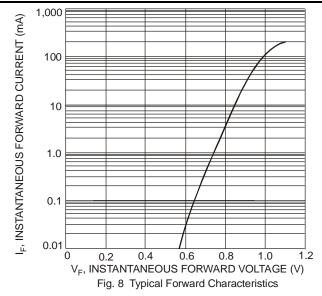








Zener Section (Z1)

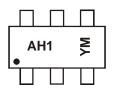


Ordering Information (Note 5)

Part Number	Case	Packaging
DVRN6056-7-F	SOT-26	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

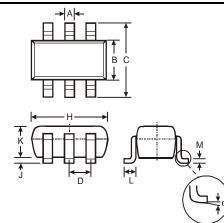
Marking Information



AH1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: P = 2003) M = Month (ex: 9 = September)

Date Code Ke	y													
Year	2003	2004	2005	2006	2007	2008	20	09	2010	201	1 201	2 2013	2014	2015
Code	Р	R	S	Т	U	V	V	V	Х	Y	Z	A	В	С
Month	Jan	Feb	Mar	Apr	Ma	v l	un	J		Aug	Sep	Oct	Nov	Dec
	Jan	Teb	IVIAI		IVIA	y 5		5		Aug	Sep	001		Dec
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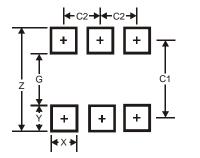
Package Outline Dimensions



	SOT-26							
Dim	Min	Max	Тур					
Α	0.35	0.50	0.38					
в	1.50	1.70	1.60					
С	2.70	3.00	2.80					
D			0.95					
Н	2.90	3.10	3.00					
J	0.013	0.10	0.05					
Κ	1.00	1.30	1.10					
L	0.35	0.55	0.40					
Μ	0.10	0.20	0.15					
α	0°	8°	_					
All D	imensi	ons in	mm					



Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

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